

## Structural Elucidation of NASICON ( $\text{Na}_3\text{Al}_2\text{P}_3\text{O}_{12}$ ) Based Glass Electrolyte Materials: Effective Influence of Boron and Gallium

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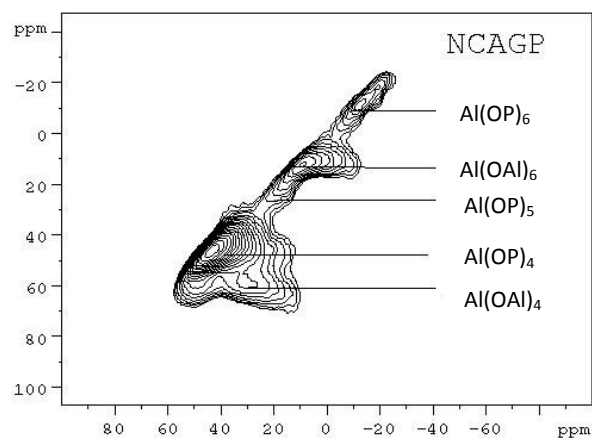
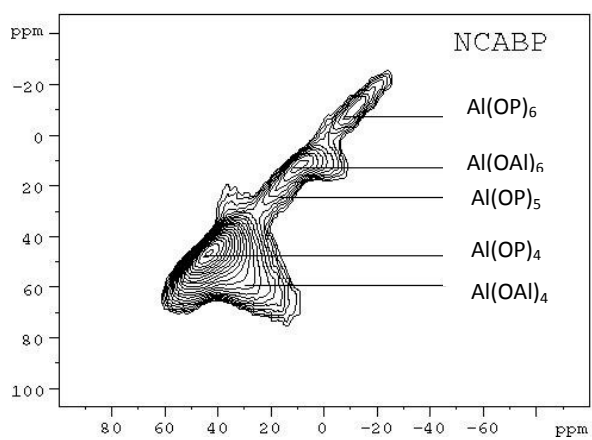
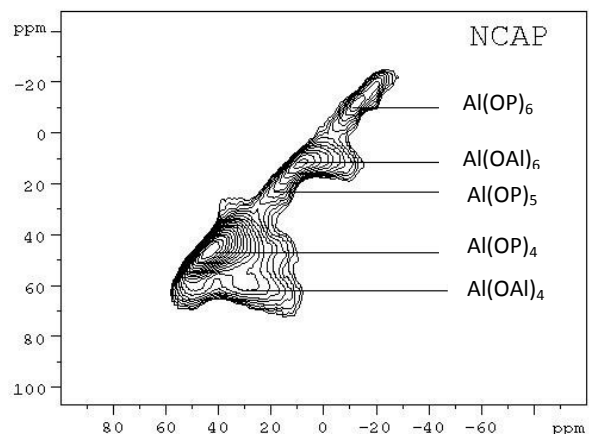


Figure S1.  $^{27}\text{Al}$  3Q MAS NMR spectra.

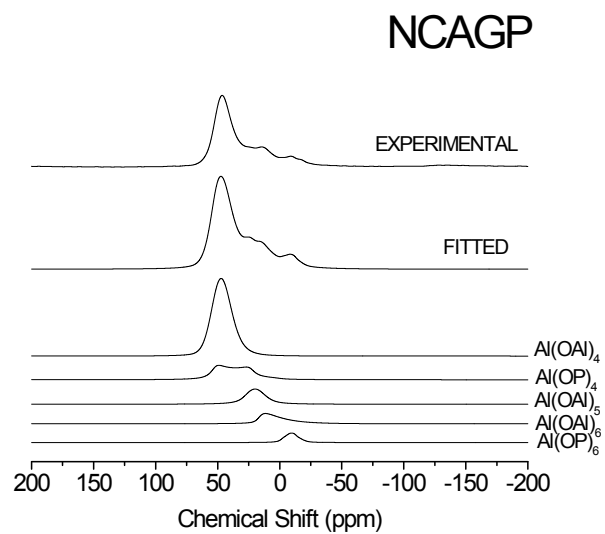
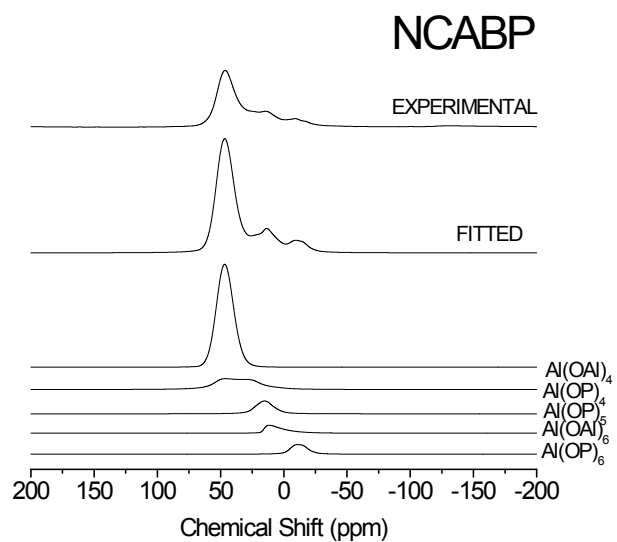
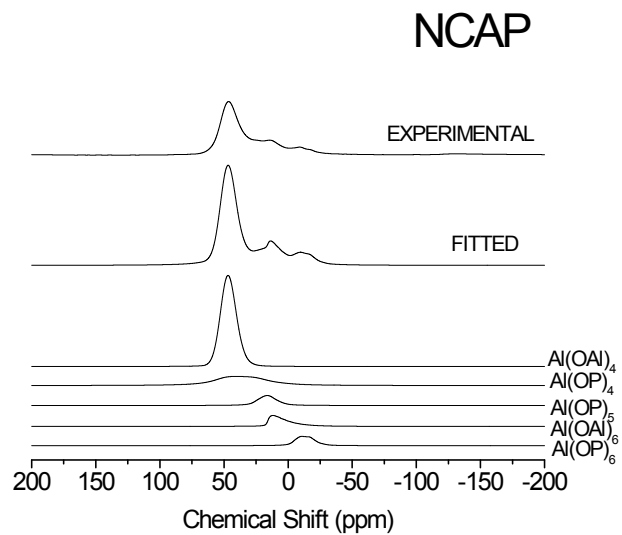
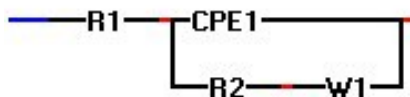


Figure S2: Deconvolution of  $^{27}\text{Al}$  MAS-NMR spectra.

## Impedance analysis:

Equivalent Circuit:



R1: Series resistance

R2: Charge transfer resistance

W1: Warburg resistance

CPE1: Constant Phase Element, used to describe the double layer capacitance at Ag/electrolyte(NASICON glass) interface (for  $n=1$ , CPE1 describes an ideal capacitor and for  $n=0$ , CPE1 describes an ideal resistor)

**Table S1:** Fitted values for the equivalent circuit.

	R1 (Ohm)	R2 (Ohm)	W1 (Ohm)	CPE1 (Farad)	n
NCAP	73106	7.48 e6	1.81 e7	4.29 e-11	0.7758
NCAGP	201330	1.03 e7	2.15 e7	4.42 e-11	0.7761
NCABP	26966	1.60 e7	1.23 e7	4.26 e-11	0.7791